

3-phase bridge rectifier + brake chopper +3-phase

bridge inverter SK 15 DGDL 126 ET

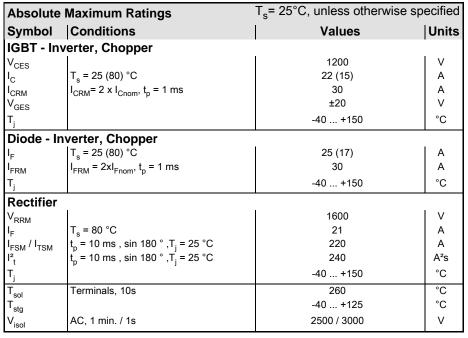
Preliminary Data

Features

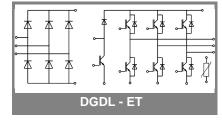
- · Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded alumium oxide ceramic (DCB)
- Trench technology IGBT
- CAL High Density FWD
- Integrated NTC temperature sensor

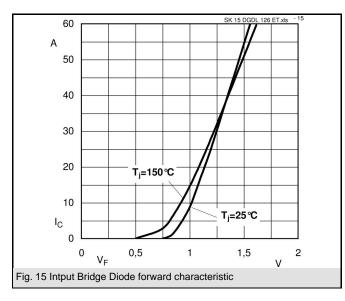
Typical Applications*

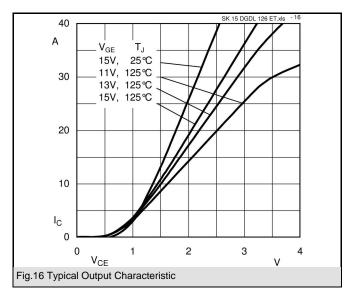
Inverter

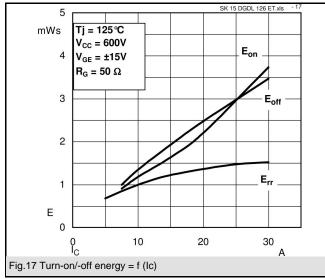


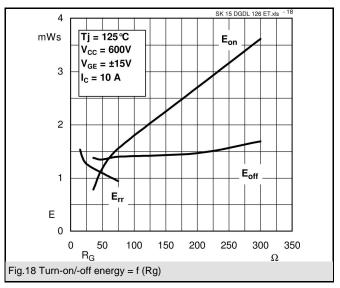
Characteristics		T _s = 25°C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V_{CEsat}	I _C = 15 A, T _j = 25 (125) °C		1,7 (2)	2,1	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 0.6$ mA	5	5,8	6,5	V
$V_{CE(TO)}$	T _j = 25 °C (125) °C		1 (0,9)		V
r _T	$T_j = 25 ^{\circ}\text{C} (125) ^{\circ}\text{C}$		45 (70)		mΩ
C _{ies}	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		1,2		nF
C _{oes}	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		0,1		nF
C _{res}	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		9,1		nF
R _{th(j-s)}	per IGBT			1,6	K/W
$t_{d(on)}$	under following conditions		25		ns
t _r	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		25		ns
$t_{d(off)}$	$I_C = 15 \text{ A}, T_j = 125 ^{\circ}\text{C}$		385		ns
t _f	$R_{Gon} = R_{Goff} = 30 \Omega$		90		ns
E _{on}	inductive load		2		mJ
E _{off}			1,8		mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	I _F = 15 A, T _j = 25(125) °C		1,6 (1,6)		V
$V_{(TO)}$	$T_j = 25 ^{\circ}\text{C} (125) ^{\circ}\text{C}$		1 (0,8)		V
r _T	T _j = 25 °C (125) °C		40 (53)		mΩ
$R_{\text{th(j-s)}}$	per diode			2,1	K/W
I _{RRM}	under following conditions		25		Α
Q_{rr}	I _F = 15 A, V _R = 600 V		3		μC
E _{rr}	V _{GE} = 0 V, T _j = 125 °C		1,1		mJ
	di _{F/dt} = 900 A/μs				
Diode rectifier					
V_{F}	I _F = 15 A, T _i = 25() °C		1,1		V
V _(TO)	T _i = 150 °C		0,9		V
r _T	T _i = 150 °C		20		mΩ
$R_{th(j-s)}$	per diode			2	K/W
Temperatur sensor					
R _{ts}	5 %, T _r = 25 (100) °C		5000(493)		Ω
Mechanical data					
w			30		g
M_s	Mounting torque			2,5	Nm

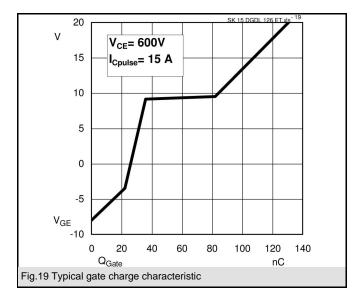


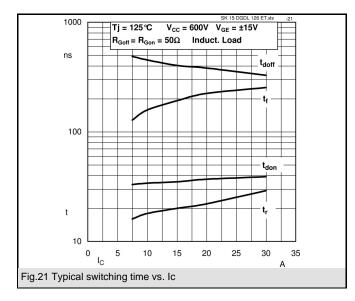


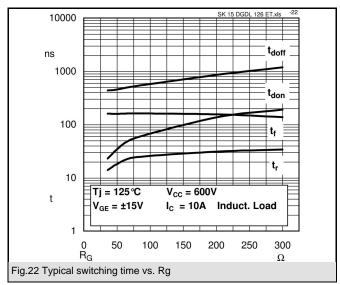


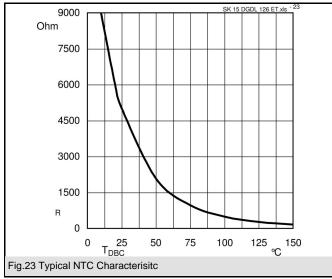


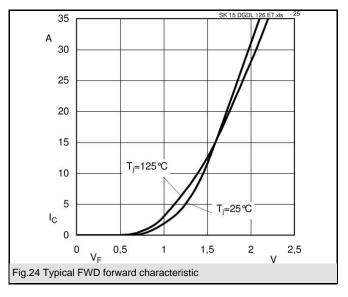




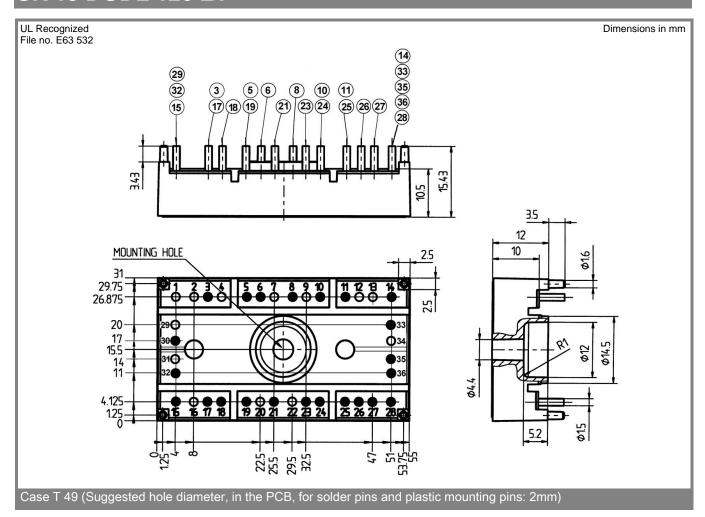


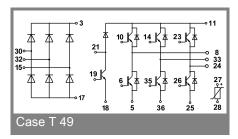






3 02-04-2009 DIL © by SEMIKRON





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.